Possibility of measuring intrinsic electronic correlations in graphene using a *d*-wave contact Josephson junction

Annica M. Black-Schaffer*

Department of Applied Physics, Stanford University, Stanford, California 94305, USA

Sebastian Doniach

Departments of Physics and Applied Physics, Stanford University, Stanford, California 94305, USA (Received 28 October 2009; published 20 January 2010)

Using a tight-binding Bogoliubov–de Gennes formalism we show that nearest-neighbor spin-singlet (SB) correlations in graphene strongly enhance proximity effect and Josephson current in unconventional *d*-wave contact graphene Josephson junctions. We also establish a $1/(T-T_c)$ functional dependence for the superconducting decay length, where T_c is the superconducting transition temperature for the intrinsic SB correlations. We therefore propose that these junctions will provide a promising experimental system for measuring the effective strength of the intrinsic SB correlations in graphene.

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I. INTRODUCTION

Graphene is a single layer of carbon atoms arranged in a honeycomb lattice and has since its isolation¹ spurred a lot of attention.^{2,3} Especially interesting are its two dimensionality and, for condensed-matter physics, peculiar band structure where the low energy excitations are massless Dirac quasiparticles which have a linear dispersion and a Fermi velocity $v_F \sim c/300$. In comparison with quantum electrodynamics (QED), this low value for v_F gives a large fine-structure constant for graphene, $\alpha_g \sim 2$, and thus Coulomb interaction effects are expected to be strong. Recently this fact has been studied in terms of the possibility of Coulomb interactions driving undoped graphene insulating through correlations in the electron-hole channel,⁴⁻⁷ but, in general, the effect of electronic interactions in graphene has largely been ignored. The standpoint was, however, quite different in the early treatments of planar organic $p\pi$ -bonded molecules of which graphene is the infinite extension. Based on experimental evidence, Pauling⁸ among others, argued then for the importance of nearest-neighbor spin-singlet bond (SB) correlations in these materials. This was the earliest incarnation of the resonance valence bond (RVB) idea, later revived by Anderson⁹ as a mechanism for superconductivity in the high- T_c cuprate superconductors. In 2002 Baskaran¹⁰ proposed a Hamiltonian which phenomenologically incorporates an effective $JS_i \cdot S_i$ term (S_i is the spin of atom i, and i and j are nearest neighbors), ultimately derived from Coulomb interactions, as a model with which to estimate the SB correlations in graphene. A few years ago, we studied the Cooper pairing channel of this Hamiltonian in mean-field theory and showed that a superconducting gap with *d*-wave symmetry develops below T_c , where T_c increases with the level of doping of the graphene.¹¹ In the bulk, the d-wave state takes the form $d_{x^2-y^2}+id_{xy}$ and thus breaks time-reversal symmetry. Recently this state has theoretically been shown to survive on-site Coulomb repulsion¹² as well as to emerge as an instability in a functional renormalization-group flow,¹³ results that further strengthen the argument that these superconducting correlations are important in graphene.

There have been reports of granular superconductivity in graphite,¹⁴⁻¹⁶ as well as a possible interfacial superconducting state between graphite and sulfur in the graphite-sulfur composites.^{15,17,18} Both of these might be experimental realizations of the intrinsic SB mechanism,¹¹ but more experimental data is needed in order to establish such a conclusion. From an experimental point of view, the main obstacle to reach the SB superconducting regime in graphene is that a very heavy doping is needed for an experimentally measurable T_c . The most frequently used method of applying a gate voltage does not nearly induce enough carriers into the graphene whereas chemical doping often faces significant material science problems and can also produce unwanted changes in other physical properties of the graphene. An exception to the latter possibly being sulfur doping¹¹ which offers an explanation to the experimental results for the graphite-sulfur composites mentioned above. Another viable approach would be to search for systems where the effect of the SB pairing correlations is naturally enhanced. One obvious candidate would be superconducting graphene. Induced superconductivity was recently demonstrated in graphene superconductor-normal metal-superconductor (SNS) Josephson junctions manufactured by depositing conventional superconducting contacts on top of the graphene.¹⁹ However, we recently showed that there is no enhancement of the SB correlations in conventional s-wave contact junctions.²⁰ The primary source for this behavior is the incompatibility between the *d*-wave symmetric SB state and the *s*-wave superconducting contacts. It is therefore logical to expand our previous study to include unconventional superconducting contacts where the symmetry of the contacts matches that of the SB superconducting state.

Using the tight-binding Bogoliubov–de Gennes (TB BdG) formalism we below report on a significant enhancement of the proximity effect and Josephson current in graphene *d*-wave contact SNS Josephson junctions due to the intrinsic SB correlations. We also establish a $1/(T-T_c)$ temperature dependence for the superconducting decay length. The latter will serve as a clear cut signal of SB correlations in these junctions.



FIG. 1. The graphene honeycomb lattice (a) and schematic experimental setup (b) and model setup (c) for a *d*-wave contact graphene SNS Josephson junction.

II. METHOD

We start with the phenomenological Hamiltonian for graphene proposed by Baskaran,¹⁰

$$H = -t \sum_{\langle \mathbf{i}, \mathbf{j} \rangle, \sigma} (f^{\dagger}_{\mathbf{i}\sigma} g_{\mathbf{j}\sigma} + g^{\dagger}_{\mathbf{i}\sigma} f_{\mathbf{j}\sigma}) + \sum_{\mathbf{i}, \sigma} \mu(\mathbf{i}) (f^{\dagger}_{\mathbf{i}\sigma} f_{\mathbf{i}\sigma} + g^{\dagger}_{\mathbf{i}\sigma} g_{\mathbf{i}\sigma}) - \sum_{\langle \mathbf{i}, \mathbf{i} \rangle} 2J(\mathbf{i}) h^{\dagger}_{\mathbf{i}\mathbf{j}} h_{\mathbf{i}\mathbf{j}}.$$
(1)

Here $f_{\mathbf{i},\sigma}^{\dagger}$ and $g_{\mathbf{i}\sigma}^{\dagger}$ are the creation operators on the two inequivalent lattice sites of the honeycomb lattice, see Fig. 1(a), t=2.5 eV is the hopping parameter, $\langle \mathbf{i}, \mathbf{j} \rangle$ indicates nearest neighbors, and μ is the effective chemical potential where $\mu=0$ corresponds to the Dirac point. The SB correlations are modeled by the last term where $h_{\mathbf{ij}}^{\dagger} = (f_{\mathbf{i}\uparrow}^{\dagger}g_{\mathbf{j}\downarrow}^{\dagger})$ $-f_{\mathbf{i}\downarrow}^{\dagger}g_{\mathbf{j}\uparrow}^{\dagger})/\sqrt{2}$ is the spin-singlet creation operator on the bond between atoms **i** and **j**. Note that

$$-Jh_{\mathbf{ij}}^{\dagger}h_{\mathbf{ij}} = J\left(\mathbf{S}_{\mathbf{i}}\cdot\mathbf{S}_{\mathbf{j}} - \frac{1}{4}n_{\mathbf{i}}n_{\mathbf{j}}\right),\tag{2}$$

where n_i is the number operator. Therefore, the last term in Eq. (1) both effectively models the SB correlations and shows its Cooper pairing nature. The effective coupling constant J has been estimated to be as large as t.¹⁰ Using $\Delta_{Ja}(\mathbf{i}) = -\sqrt{2}J(\mathbf{i})\langle h_{\mathbf{i},\mathbf{i}+\mathbf{a}} \rangle$ as the mean-field order parameter, Eq. (1) can solved with a double Bogoliubov-Valatin transformation.²² Here **a** denotes the nearest-neighbor bond, see again Fig. 1(a), and we allow the order parameter to be independent on the three bonds. The most favorable superconducting state in the bulk has $\Delta_{Ja} \propto (1, e^{i2\pi i/3}, e^{i4\pi i/3})$ which corresponds to a $d_{x^2-y^2}+id_{xy}$ -wave symmetry in the Brillouin zone. As long as J > 0 this state has a finite T_c for any finite doping level and T_c increases rapidly with either hole or electron doping.¹¹

In addition to Eq. (1), the influence of the superconducting contacts, deposited on top of the graphene sheet as shown in Fig. 1(b), has to be taken into account. We do this by assuming that the contacts induce into the *S* regions of the graphene (a) an effective paring potential and (b) a high doping level. For *d*-wave contacts the simplest effective pairing potential is the same *J* term as for the intrinsic SB correlations. We therefore chose to model the effect of the contacts

with a strong J-term in the S regions [see Fig. 1(c)]. The particular *d*-wave symmetry in the S regions is fixed to the $d_{x^2-y^2}$ -wave on the zigzag interface which is achieved by setting $\Delta_{Ja} \propto (2, -1, -1)$.^{11,21} We have checked that a 90° rotation of either interface or *d*-wave symmetry produces no notable change in the proximity effect. Note that the choice of *d*-wave symmetry is still unrestricted in the *N* region, though with the symmetry fixed in the S regions and relatively short junctions, the same symmetry choice in N is now energetically favored. We should also note that we have used an artificially high value for J in S in order to get a short superconducting coherence length ξ in S and therefore reduce the computational size of the problem. However, we believe our conclusions are still applicable for an experimental setup with, e.g., a *d*-wave high- T_c cuprate superconductor as the contact metal, since the only essential feature of the contacts is to produce a stable *d*-wave superconducting state in the S regions for all temperatures considered. The doping is set to be high in the S regions since the superconducting contacts act as large electronic reservoirs directly in contact with the graphene. In the N region we assume that the doping level is finite in order to produce a nonzero T_c for the intrinsic SB correlations. Please note that despite a finite T_c we will continue to refer to this region as N as in "normal" to simplify the notation. In fact, the doping in the N region is kept moderately high in our calculations in order to deal with numerically accessible T_c s for the SB superconductivity. But, since our results below use only T_c as the relevant SB parameter, this should not affect the generalization of the results to a more realistic lower doping regime. We assume that the effective chemical potential abruptly drops at the SN interfaces. While this is a simplification, a moderate leakage of charge from S to N would only raise the intrinsic T_c in the interface region and thus enhance the SB pairing effect. We also assume clean, smooth interfaces, which allows for the application of Bloch's theorem in the direction along the interfaces. This considerably reduces the computational effort but we do not expect a moderately disordered interface to significantly change our results as previously shown.²⁰

The above framework can be solved self-consistently for the position-dependent $\Delta_{Ja}(\mathbf{i})$ using the TB BdG formalism for ballistic graphene SNS Josephson junctions.^{20–22} It is the use of an effective pairing potential instead of an effective order parameter in the S regions that allows us to solve selfconsistently for the order parameter. This leads to a selfconsistent calculation of the proximity-effect depletion in S and leakage into N of the pair amplitude $F_{Ja} = \Delta_{Ja} / (\sqrt{2}J)$ and its norm $F = \sqrt{|F_{Ja_1}|^2 + |F_{Ja_2}|^2 + |F_{Ja_3}|^2}$, as seen below in Fig. 2. This should be compared to the analytical Dirac-BdG formalism developed for graphene SNS Josephson junctions^{23,24} where the order parameter is assumed to be constant in the S regions. Not only is a self-consistent solution necessary for studying the coupling between the externally induced d-wave state and the SB pairing correlations but a recent comparison between the two methods has also demonstrated the necessity for a self-consistent solution when unconventional contacts are considered.²¹ Not only can we explicitly calculate the proximity effect self-consistently but by also applying a phase difference in Δ_{Ia} between the two S regions, a supercurrent will flow through the junction. This Josephson cur-



FIG. 2. (Color online) Proximity effect in terms of the norm of the pair amplitude *F* normalized to the bulk value in the contacts F_0 when SB correlations are ignored, i.e., J(N)=0 (black), and when SB correlations are present with J(N)=t (red) at temperatures T=0.6 T_c (solid) and $T=17T_c$ (dashed), with T_c being the transition temperature when J(N)=t. Vertical lines indicate the SN interfaces. The junction length is L=30 unit cells to be compared with $\xi=5$ unit cells in the *S* regions. The inset shows a magnification over the *N* region.

rent can relatively straightforwardly be calculated, without any further approximations, using the continuity equation and the Heisenberg equation for the electron density (see Ref. 22 for further details).

III. RESULTS

The most straightforward physical quantity to study in the TB BdG framework is the proximity effect, or more specifically, the Cooper pair amplitude distribution in the SNS junction. If a measurable signal of SB correlations were found in this quantity, there ought to be signs in other, more easily experimentally measurable, quantities such as the local density of states (LDOS) and the Josephson current. Figure 2 shows the norm of the pair amplitude F for a d-wave contact SNS junction. In black are the results when the SB correlations are ignored, i.e. J(N)=0, at two different temperatures and, as seen, the results are essentially temperature independent in this particular range. When SB correlations are included (red) the pair amplitude in N increases. The pair amplitude inside N is in fact larger by almost an order of a magnitude than it would have been in a bulk sample with the same strength SB pairing. This means that in *d*-wave contact SNS junctions the intrinsic SB pairing is heavily benefitting from the proximity to the superconducting contacts. This is despite the large Fermi-level mismatch (FLM) at the SN interfaces, due to different doping levels in S and N, which acts as an effective interface barrier.²¹ However, since the extrinsic superconducting state and the intrinsic SB pairing here by design have the same symmetry this is probably not a too surprising result. More interesting is the temperature scale over which this enhanced SB pairing takes place. The solid curves are for $T=0.6T_c$, i.e., when the doping level is sufficient for intrinsic SB superconductivity to be present, and the dashed curves are recorded when $T=17T_c$. We thus see a strongly enhanced proximity effect in the SNS junction even far above T_c .



FIG. 3. (Color online) Superconducting decay length ξ_n as a function of scaled inverse temperature $t/(k_BT)$ for J(N)=0 (black, circles) and J(N)>0 (colors, crosses) with increasing transition temperatures T_c achieved by increasing J(N) (yellow, cyan, blue, red, and green). Increasing the doping level in N instead (magenta) produces the same result. Vertical lines indicate the corresponding T_c s. The inset shows the linear behavior of ξ_n vs $t/(k_B(T-T_c))$ at moderately to large $(T-T_c)$.

One very closely related, but easier quantifiable, property to the proximity effect is the superconducting decay length, or normal-state coherence length ξ_n , which is the length scale over which the pairing amplitude (exponentially) decay inside N,

$$F \propto e^{-x/\xi_n}.$$
 (3)

Figure 3 shows the inverse temperature dependence of ξ_n for several different strengths of the intrinsic SB pairing. In black circles are the results when SB correlations are ignored whereas colored crosses show the results when they are present with the vertical lines indicating the corresponding intrinsic T_c . The almost overlaying red and magenta curves correspond to the same T_c but achieved through different combinations of SB correlation strength J and doping level in N, which demonstrates the dependence on T_c only. From the figure we clearly see that to a good approximation ξ_n $\propto 1/T$ in the uncorrelated case. For any finite SB pairing inside N, ξ_n will diverge at the corresponding intrinsic T_c leading to a giant proximity effect for temperatures close to T_c . The same diverging behavior has recently also been predicted for the square lattice for both s-wave and d-wave contact SNS junctions when the N region exhibits weak superconductivity of the same symmetry,²⁵ although this study was conducted with no FLM at the SN interfaces. The increase in proximity effect far above T_c documented in Fig. 2 is here reflected in an increased decay length even at elevated temperatures. The inset in Fig. 3 shows that for temperatures moderately to high above T_c we can extract the following functional form for the superconducting decay length,

$$\xi_n \propto \frac{1}{T - T_c}.\tag{4}$$

The limited accuracy due to finite model systems makes our numerical data deviate from this relationship at temperatures



FIG. 4. (Color online) Critical current I_c in units of $I_0 = eW/(\hbar\xi)$, where W is the width of the junction and when v_F is set to 1, for J(N)=0 (circles) and J(N)=t (crosses). Different colors represent increasing doping levels (black, red, and green) in N. The corresponding T_c s are marked with vertical lines. The junction length is L=30 unit cells to be compared to $\xi=5$ unit cells.

close to T_c , but we expect Eq. (4) to be valid even as T $\rightarrow T_c$. From this we can conclude that any evidence of a divergence in ξ_n at a nonzero temperature with a $1/(T-T_c)$ functional form in a *d*-wave contact graphene SNS junction would be a clear measurement of the strength of the intrinsic SB correlations in graphene. For example, a scanning tunneling spectroscopy measurement of the LDOS as function of the distance from the interface in a SN junction should provide experimental access to the superconducting decay length. Note however that the $d_{x^2-y^2}$ -wave order parameter has an effective p_{y} -wave symmetry at the Fermi surfaces of graphene²⁰ since these are centered around the corners of the Brillouin zone, and therefore nodes are present in the superconducting energy gap. Representative LDOS calculations for SNS junctions have recently been reported in Refs. 20 and 21.

It would also be useful to characterize the effect of SB correlations on the most accessible property of a SNS junction, namely the Josephson current. Figure 4 shows the critical current as a function of temperature when SB correlations are ignored (circles) and present (crosses) for three different

doping levels in *N*. The corresponding T_c s for the SB pairing are again marked with vertical lines. As seen, the Josephson current increases with decreasing temperatures in all cases. This is expected since ξ_n is inversely proportional to the temperature. There is also a pronounced increase in the current when SB correlations are present in the junction, and, most importantly, the current is now enhanced even far above T_c , a direct consequence of the increased decay length for finite T_c . For systems with strong SB correlations, the current increases more compared to the uncorrelated case at and below T_c . This effect is not due to the decay length per see, since ξ_n diverges at T_c for all strengths of the SB correlations, but related to the strength of the intrinsic SB superconducting state in *N* which is reached for $T < T_c$.

IV. CONCLUSIONS

The results in Figs. 2-4 clearly demonstrate that the intrinsic SB correlations in graphene greatly enhance the superconducting properties of graphene d-wave contact SNS Josephson junctions even far above their intrinsic T_c . Since the intrinsic SB correlations at the currently experimentally fairly limited doping levels of graphene are expected to be rather weak, this enhancement far above T_c is crucial for any experimental detection. Especially a measurement of the temperature dependence of the decay length, as seen in Fig. 3, should provide a straightforward estimation of the intrinsic T_c of the SB correlations. We have here predicted that this temperature dependence changes from 1/T to $1/(T-T_c)$ when finite SB correlations are considered. As it is straightforward, at least on a mean-field level, to related a finite T_c to the effective SB coupling J at a known doping level, the findings of a finite T_c in a graphene *d*-wave contact SNS Josephson junction will directly establish the strength of J. An experimental detection of a finite T_c and the subsequent estimation of the coupling constant J would fundamentally change the current view of graphene to that of a strongly correlated material.

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- *Present address: NORDITA, Roslagstullsbacken 23, S-10691 Stockholm, Sweden.
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